

III. Fast / Ultra Fast / Super Fast Recovery Rectifier

5.0A Surface Mount Ultra Fast Recovery Rectifier

US5AB~US5MB

(Package: SMB (DO-214AA))

<p>FEATURES</p> <ul style="list-style-type: none"> • For surface mounted applications. • Glass passivated junction chip. • Built-in strain relief, ideal for automated placement. • Plastic material used carries Underwriters Laboratory Flammability Classification 94V-0. • Ultra Fast recovery for high efficiency. • High temperature soldering : 250 °C /10 seconds at terminals. <p>MECHANICAL DATA</p> <ul style="list-style-type: none"> • Case : Molded plastic • Terminals : Solder plated • Polarity : Indicated by cathode band • Weight : 0.090 grams 	<p>Case: SMB Dimensions in inches and (millimetres)</p>
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Ratings & Electrical Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20%.

Characteristics	Symbol	US5AB	US5BB	US5DB	US5GB	US5JB	US5KB	US5MB	Units			
Maximum recurrent peak reverse voltage	V _{RRM}	50	100	200	400	600	800	1000	Volts			
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	Volts			
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	1000	Volts			
Maximum average forward rectified current See Fig. 1 @ T _L =110	I _o	5.0						Amps				
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load. (JEDEC Method)	I _{FSM}	150						Amps				
Maximum instantaneous forward voltage @ 5.0 A	V _F	1.0		1.4	1.85			Volts				
Maximum DC reverse current @ T _a =25 at rated DC blocking voltage @ T _a =100	I _R	10.0 250						µA				
Maximum reverse recovery time (Note 1)	T _{rr}	50			100			ns				
Typical junction capacitance (Note 2)	C _j	98			82			PF				
Typical thermal resistance	R _{th-JA}	47						/W				
Operating temperature range	T _j	-65 to +150										
Storage temperature range	T _{stg}	-65 to +150										

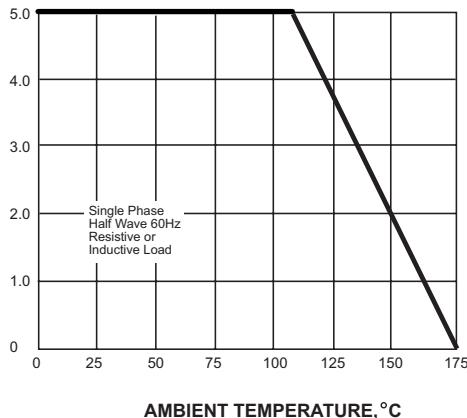
Notes:

1. Reverse recovery test conditions: I_F=0.5A, I_R=1.0A, I_{RR}=0.25A
2. Measured at 1.0 MHz and applied V_R=4.0V.

Ratings and Characteristic Curves of US5AB~US5MB

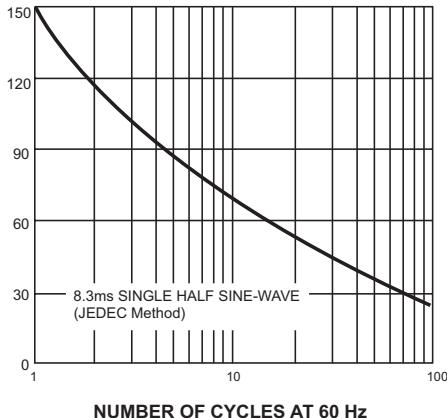
AVERAGE FORWARD RECTIFIED CURRENT,
AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



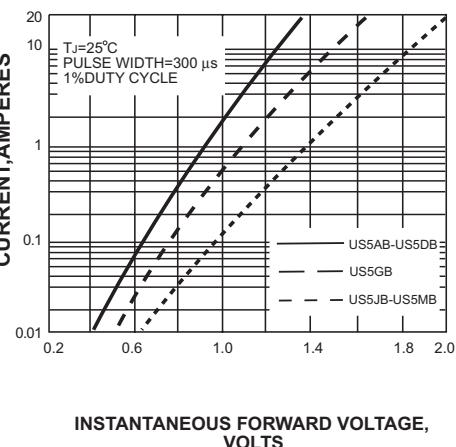
PEAK FORWARD SURGE CURRENT,
AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



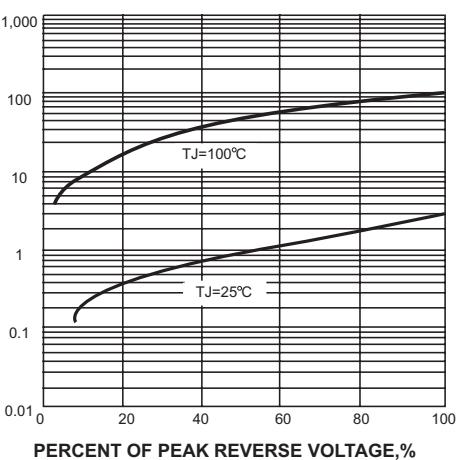
INSTANTANEOUS FORWARD
CURRENT, AMPERES

FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



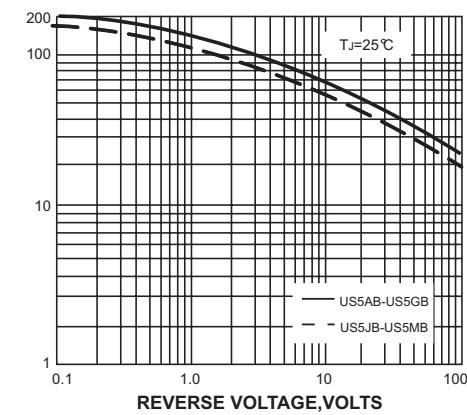
INSTANTANEOUS REVERSE CURRENT,
MICROAMPERES

FIG. 4-TYPICAL REVERSE CHARACTERISTICS



JUNCTION CAPACITANCE, pF

FIG. 5-TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE,
°C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE

